RN2427TE85LF

RN2427TE85LF Information

For Reference Only

Part Number RN2427TE85LF
Manufacturer Toshiba Semiconductor and Storage
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Single, Pre-Biased
Description TRANS PREBIAS PNP 200MW SMINI
Package TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

RN2427TE85LF Specifications

Manufacturer Part Number	RN2427TE85LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	PNP - Pre-Biased
Current - Collector (Ic) (Max)	800mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	2.2k
Resistor - Emitter Base (R2) (Ohms)	10k
DC Current Gain (hFE) (Min) @ Ic, Vce	90 @ 100mA, 1V
Vce Saturation (Max) @ Ib, Ic	250mV @ 1mA, 50mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	200MHz
Power - Max	200mW
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	S-Mini
	Report errors?

RN2427TE85LF Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

RN2427TE85LF Payment Methods

RN2427TE85LF Shipping Methods

If you have any question about RN2427TE85LF, please do not hesitate to contact us!
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